Semiconductor Device Set - Page 1 of 1



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## **Inclosure Material:** Metal all transistor **Overall Length:** 0.697 inches all transistor and 0.730 inches all transistor **Overall Height:** 0.229 inches all transistor and 0.290 inches all transistor **Overall Width:** 0.970 inches all transistor and 1.143 inches all transistor **Mounting Facility Quantity:** 2 all transistor Internal Configuration: Junction contact all transistor **Internal Junction Configuration:** Npn all transistor **Component Function Relationship:** Matched **Component Name And Quantity:** 2 transistor **Mounting Method:** Unthreaded hole all transistor **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 110.0 collector to base voltage/static/emitter open all transistor and 55.0 collector to emitter voltage/static/base open all transistor and 4.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 15.00 amperes source cutoff current all transistor **Power Rating Per Characteristic:** 300.0 watts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction all transistor **Terminal Type And Quantity:** 4 ribbon all transistor Shelf Life: N/a Unit Of Measure: --**Demilitarization:** No Fiig: A110a0